

# DATA SHEET

**74AHC3G04; 74AHCT3G04**

Inverter

Product specification

2003 Nov 06

**Inverter****74AHC3G04; 74AHCT3G04****FEATURES**

- Symmetrical output impedance
- High noise immunity
- ESD protection:
  - HBM EIA/JESD22-A114-A exceeds 2000 V
  - MM EIA/JESD22-A115-A exceeds 200 V
  - CDM EIA/JESD22-C101 exceeds 1000 V.
- Low power dissipation
- Balanced propagation delays
- SOT505-2 and SOT765-1 package
- Specified from –40 to +85 °C and –40 to +125 °C.

**DESCRIPTION**

The 74AHC3G04/74AHCT3G04 are high-speed Si-gate CMOS devices.

The 74AHC3G04/74AHCT3G04 provides three inverting buffer.

**QUICK REFERENCE DATA**

GND = 0 V; T<sub>amb</sub> = 25 °C; t<sub>r</sub> = t<sub>f</sub> ≤ 3.0 ns.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			74AHC3G04	74AHCT3G04	
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay input A to output Y	C <sub>L</sub> = 15 pF; V <sub>CC</sub> = 5 V	3.1	3.4	ns
C <sub>I</sub>	input capacitance		1.5	1.5	pF
C <sub>PD</sub>	power dissipation capacitance	C <sub>L</sub> = 50 pF; f = 1 MHz; notes 1 and 2	9	10	pF

**Notes**

1. C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in Volts;

N = total load switching outputs;

$\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

2. The condition is V<sub>I</sub> = GND to V<sub>CC</sub>.

**FUNCTION TABLE**

See note 1.

INPUT	OUTPUT
nA	nY
L	H
H	L

**Note**

1. H = HIGH voltage level;  
L = LOW voltage level.

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## 74AHC3G04; 74AHCT3G04

## ORDERING AND PACKAGE INFORMATION

TYPE NUMBER	PACKAGES					
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE	MARKING
74AHC3G04DP	-40 to +125 °C	8	TSSOP8	plastic	SOT505-2	A04
74AHCT3G04DP	-40 to +125 °C	8	TSSOP8	plastic	SOT505-2	C04
74AHC3G04DC	-40 to +125 °C	8	VSSOP8	plastic	SOT765-1	A04
74AHCT3G04DC	-40 to +125 °C	8	VSSOP8	plastic	SOT765-1	C04

## PINNING

PIN	SYMBOL	DESCRIPTION
1	1A	data input
2	3Y	data output
3	2A	data input
4	GND	ground (0 V)
5	2Y	data output
6	3A	data input
7	1Y	data output
8	V <sub>CC</sub>	supply voltage

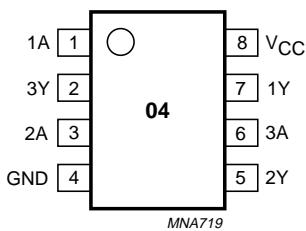


Fig.1 Pin configuration.

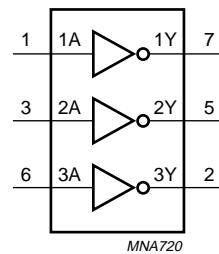
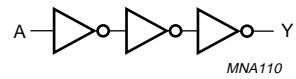
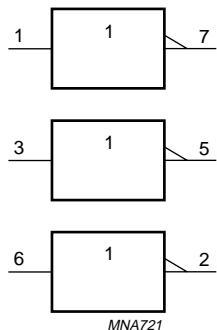


Fig.2 Logic symbol.

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74AHC3G04; 74AHCT3G04



## RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	74AHC3G04			74AHCT3G04			UNIT
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
$V_{CC}$	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
$V_I$	input voltage		0	—	5.5	0	—	5.5	V
$V_O$	output voltage		0	—	$V_{CC}$	0	—	$V_{CC}$	V
$T_{amb}$	operating ambient temperature	see DC and AC characteristics per device	-40	+25	+125	-40	+25	+125	°C
$t_r, t_f (\Delta t/\Delta f)$	input rise and fall times	$V_{CC} = 3.3 \pm 0.3$ V	—	—	100	—	—	—	ns/V
		$V_{CC} = 5 \pm 0.5$ V	—	—	20	—	—	20	ns/V

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CC}$	supply voltage		-0.5	+7.0	V
$V_I$	input voltage		-0.5	+7.0	V
$I_{IK}$	input diode current	$V_I < -0.5$ V	—	-20	mA
$I_{OK}$	output diode current	$-0.5$ V < $V_O < V_{CC} + 0.5$ V; note 1	—	$\pm 20$	mA
$I_O$	output source or sink current	$-0.5$ V < $V_O < V_{CC} + 0.5$ V	—	$\pm 25$	mA
$I_{CC}, I_{GND}$	$V_{CC}$ or GND current		—	$\pm 75$	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_D$	power dissipation	$T_{amb} = -40$ to $+125$ °C	—	250	mW

## Note

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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## DC CHARACTERISTICS

## Type 74AHC3G04

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V <sub>CC</sub> (V)				
<b>T<sub>amb</sub> = 25 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		2.0	1.5	—	—	V
			3.0	2.1	—	—	V
			5.5	3.85	—	—	V
V <sub>IL</sub>	LOW-level input voltage		2.0	—	—	0.5	V
			3.0	—	—	0.9	V
			5.5	—	—	1.65	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = -50 µA	2.0	1.9	2.0	—	V
		I <sub>O</sub> = -50 µA	3.0	2.9	3.0	—	V
		I <sub>O</sub> = -50 µA	4.5	4.4	4.5	—	V
		I <sub>O</sub> = -4.0 mA	3.0	2.58	—	—	V
		I <sub>O</sub> = -8.0 mA	4.5	3.94	—	—	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = 50 µA	2.0	—	0	0.1	V
		I <sub>O</sub> = 50 µA	3.0	—	0	0.1	V
		I <sub>O</sub> = 50 µA	4.5	—	0	0.1	V
		I <sub>O</sub> = 4.0 mA	3.0	—	—	0.36	V
		I <sub>O</sub> = 8.0 mA	4.5	—	—	0.36	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND	5.5	—	—	0.1	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	—	—	10	µA
C <sub>I</sub>	input capacitance		—	—	1.5	10	pF

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SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V <sub>CC</sub> (V)				
<b>T<sub>amb</sub> = -40 to +85 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		2.0	1.5	—	—	V
			3.0	2.1	—	—	V
			5.5	3.85	—	—	V
V <sub>IL</sub>	LOW-level input voltage		2.0	—	—	0.5	V
			3.0	—	—	0.9	V
			5.5	—	—	1.65	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>					
		I <sub>O</sub> = -50 µA	2.0	1.9	—	—	V
		I <sub>O</sub> = -50 µA	3.0	2.9	—	—	V
		I <sub>O</sub> = -50 µA	4.5	4.4	—	—	V
		I <sub>O</sub> = -4.0 mA	3.0	2.48	—	—	V
		I <sub>O</sub> = -8.0 mA	4.5	3.8	—	—	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>					
		I <sub>O</sub> = 50 µA	2.0	—	—	0.1	V
		I <sub>O</sub> = 50 µA	3.0	—	—	0.1	V
		I <sub>O</sub> = 50 µA	4.5	—	—	0.1	V
		I <sub>O</sub> = 4.0 mA	3.0	—	—	0.44	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND	5.5	—	—	1.0	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	—	—	10	µA
C <sub>I</sub>	input capacitance		—	—	—	10	pF

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SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V <sub>CC</sub> (V)				
<b>T<sub>amb</sub> = -40 to +125 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		2.0	1.5	—	—	V
			3.0	2.1	—	—	V
			5.5	3.85	—	—	V
V <sub>IL</sub>	LOW-level input voltage		2.0	—	—	0.5	V
			3.0	—	—	0.9	V
			5.5	—	—	1.65	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>					
		I <sub>O</sub> = -50 µA	2.0	1.9	—	—	V
		I <sub>O</sub> = -50 µA	3.0	2.9	—	—	V
		I <sub>O</sub> = -50 µA	4.5	4.4	—	—	V
		I <sub>O</sub> = -4.0 mA	3.0	2.40	—	—	V
		I <sub>O</sub> = -8.0 mA	4.5	3.70	—	—	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>					
		I <sub>O</sub> = 50 µA	2.0	—	—	0.1	V
		I <sub>O</sub> = 50 µA	3.0	—	—	0.1	V
		I <sub>O</sub> = 50 µA	4.5	—	—	0.1	V
		I <sub>O</sub> = 4.0 mA	3.0	—	—	0.55	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND	5.5	—	—	2.0	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	—	—	40	µA
C <sub>I</sub>	input capacitance		—	—	—	10	pF

## Inverter

## 74AHC3G04; 74AHCT3G04

**Type 74AHCT3G04**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V <sub>CC</sub> (V)				
<b>T<sub>amb</sub> = 25 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		4.5 to 5.5	2.0	—	—	V
V <sub>IL</sub>	LOW-level input voltage		4.5 to 5.5	—	—	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = -50 µA I <sub>O</sub> = -8.0 mA	4.5 4.5	4.4 3.94	4.5 —	— —	V V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = 50 µA I <sub>O</sub> = 8.0 mA	4.5 4.5	— —	0 0.36	0.1 0.36	V V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	5.5	—	—	0.1	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	—	—	1.0	µA
ΔI <sub>CC</sub>	additional quiescent supply current per input pin	V <sub>I</sub> = 3.4 V; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	—	—	1.35	mA
C <sub>I</sub>	input capacitance			—	1.5	10	pF
<b>T<sub>amb</sub> = -40 to +85 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		4.5 to 5.5	2.0	—	—	V
V <sub>IL</sub>	LOW-level input voltage		4.5 to 5.5	—	—	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = -50 µA I <sub>O</sub> = -8.0 mA	4.5 4.5	4.4 3.8	— —	— —	V V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = 50 µA I <sub>O</sub> = 8.0 mA	4.5 4.5	— —	— —	0.1 0.44	V V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	5.5	—	—	1.0	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	—	—	10	µA
ΔI <sub>CC</sub>	additional quiescent supply current per input pin	V <sub>I</sub> = 3.4 V; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	—	—	1.5	mA
C <sub>I</sub>	input capacitance		—	—	—	10	pF

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## 74AHC3G04; 74AHCT3G04

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V <sub>CC</sub> (V)				
<b>T<sub>amb</sub> = -40 to +125 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		4.5 to 5.5	2.0	—	—	V
V <sub>IL</sub>	LOW-level input voltage		4.5 to 5.5	—	—	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = -50 µA I <sub>O</sub> = -8.0 mA	4.5 4.5	4.4 3.70	— —	— —	V V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = 50 µA I <sub>O</sub> = 8.0 mA	4.5 4.5	— —	— —	0.1 0.55	V V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	5.5	—	—	2.0	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	—	—	40	µA
ΔI <sub>CC</sub>	additional quiescent supply current per input pin	V <sub>I</sub> = 3.4 V; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	—	—	1.5	mA
C <sub>I</sub>	input capacitance		—	—	—	10	pF

## Inverter

## 74AHC3G04; 74AHCT3G04

## AC CHARACTERISTICS

## Type 74AHC3G04

GND = 0 V;  $t_r = t_f \leq 3.0$  ns.

SYMBOL	PARAMETER	TEST CONDITIONS			MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	C <sub>L</sub> (pF)	V <sub>CC</sub> (V)				
<b>T<sub>amb</sub> = 25 °C</b>								
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay input nA to output nY	see Figs 5 and 6	15	3.0 to 3.6	—	—	7.1	ns
				3.3	—	4.3	—	ns
				4.5 to 5.5	—	—	5.5	ns
				5	—	3.1	—	ns
			50	3.0 to 3.6	—	—	10.6	ns
				3.3	—	6.1	—	ns
				4.5 to 5.5	—	—	7.5	ns
				5	—	4.5	—	ns
<b>T<sub>amb</sub> = -40 to +85 °C</b>								
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay input nA to output nY	see Figs 5 and 6	15	3.0 to 3.6	1.0	—	8.5	ns
				4.5 to 5.5	1.0	—	6.5	ns
			50	3.0 to 3.6	1.0	—	12	ns
				4.5 to 5.5	1.0	—	8.5	ns
<b>T<sub>amb</sub> = -40 to +125 °C</b>								
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay input nA to output nY	see Figs 5 and 6	15	3.0 to 3.6	1.0	—	11.0	ns
				4.5 to 5.5	1.0	—	7.0	ns
			50	3.0 to 3.6	1.0	—	14.5	ns
				4.5 to 5.5	1.0	—	9.5	ns

## Type 74AHCT3G04

GND = 0 V;  $t_r = t_f \leq 3.0$  ns.

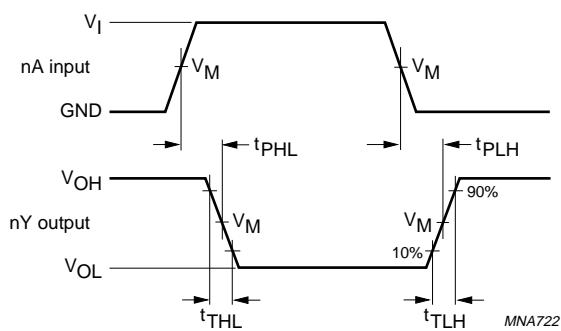
SYMBOL	PARAMETER	TEST CONDITIONS			MIN.	TYP.	MAX.	UNIT		
		WAVEFORMS	C <sub>L</sub> (pF)	V <sub>CC</sub> (V)						
<b>T<sub>amb</sub> = 25 °C</b>										
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay input nA to output nY	see Figs 5 and 6	15	4.5 to 5.5	—	—	6.7	ns		
				5	—	3.4	—	ns		
			50	4.5 to 5.5	—	—	7.7	ns		
				5	—	4.9	—	ns		
<b>T<sub>amb</sub> = -40 to +85 °C</b>										
15			4.5 to 5.5	1.0	—	7.5	ns			
			50	4.5 to 5.5	1.0	—	8.5			

## Inverter

## 74AHC3G04; 74AHCT3G04

SYMBOL	PARAMETER	TEST CONDITIONS			MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	C <sub>L</sub> (pF)	V <sub>CC</sub> (V)				
<b>T<sub>amb</sub> = -40 to +125 °C</b>								
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay input nA to output nY	see Figs 5 and 6	15 50	4.5 to 5.5 4.5 to 5.5	1.0 1.0	— —	8.5 10.0	ns ns

## AC WAVEFORMS

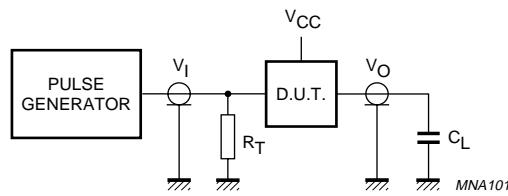


TYPE	V <sub>I</sub> INPUT REQUIREMENTS	V <sub>M</sub> INPUT	V <sub>M</sub> OUTPUT
74AHC3G04	GND to V <sub>CC</sub>	50% V <sub>CC</sub>	50% V <sub>CC</sub>
74AHCT3G04	GND to 3.0 V	1.5 V	50% V <sub>CC</sub>

Fig.5 Input (nA) to output (nY) propagation delays.

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Definitions for test circuit:

$C_L$  = load capacitance including jig and probe capacitance (see Chapter "AC characteristics").

$R_T$  = termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

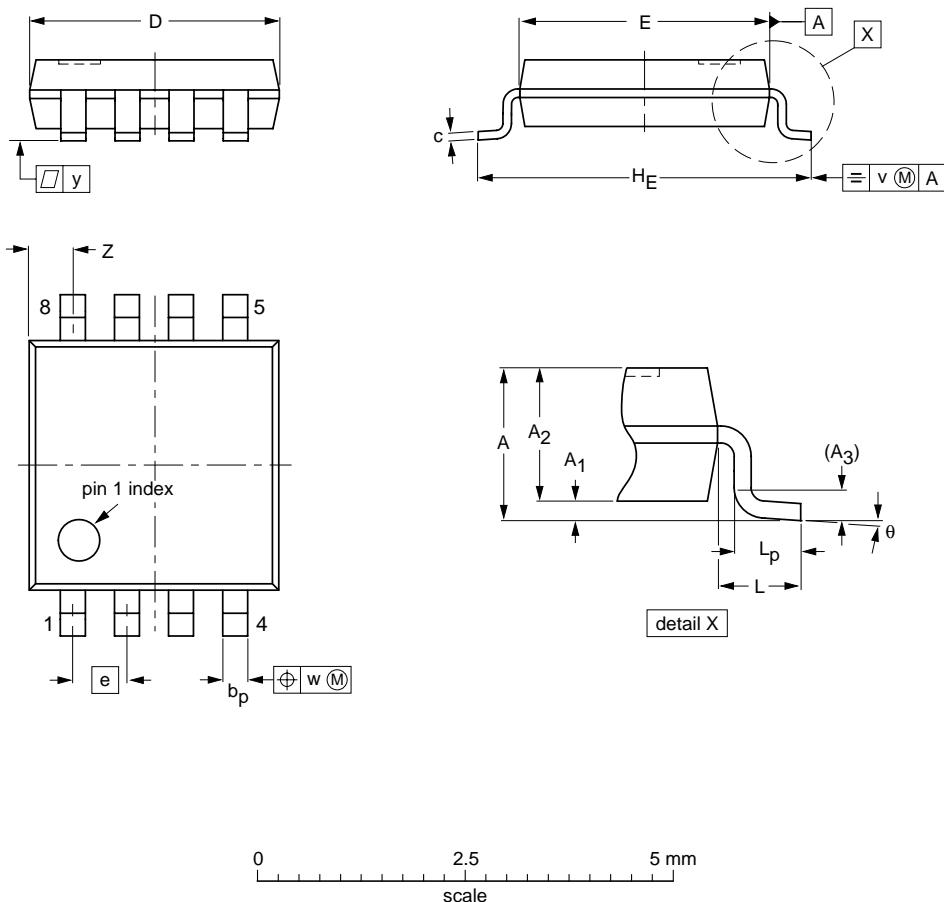
Fig.6 Load circuitry for switching times.

## Inverter

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## PACKAGE OUTLINES

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2



## DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	H <sub>E</sub>	L	L <sub>p</sub>	v	w	y	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.00	0.95 0.75	0.25	0.38 0.22	0.18 0.08	3.1 2.9	3.1 2.9	0.65	4.1 3.9	0.5	0.47 0.33	0.2	0.13	0.1	0.70 0.35	8° 0°

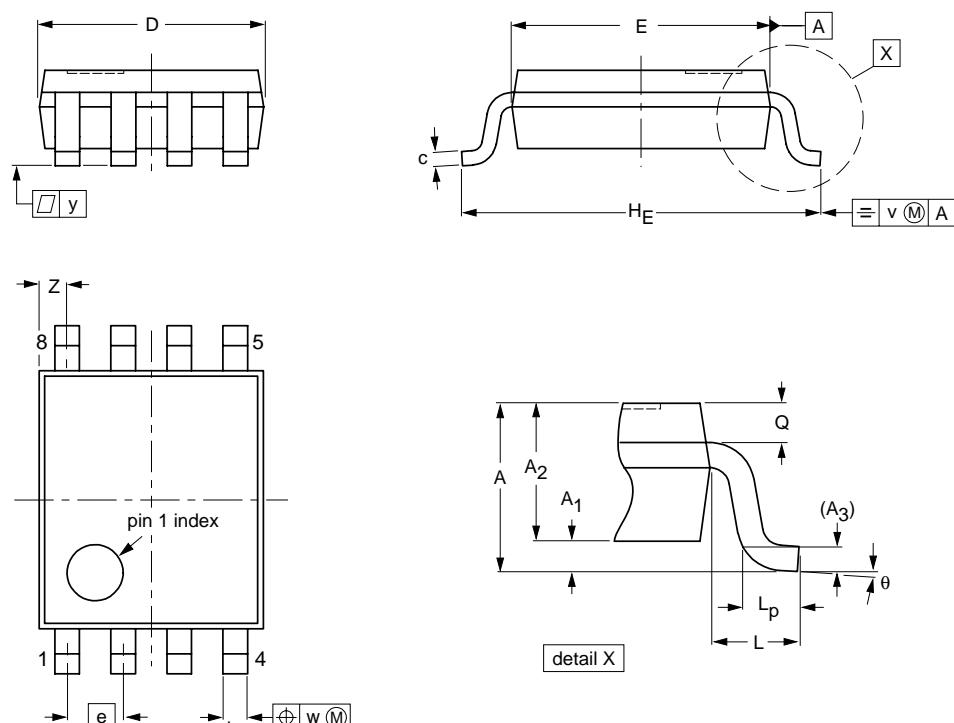
## Note

- Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT505-2		---				02-01-16

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**VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm****SOT765-1**

0                          2.5                          5 mm  
scale

**DIMENSIONS (mm are the original dimensions)**

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	c	D <sup>(1)</sup>	E <sup>(2)</sup>	e	H <sub>E</sub>	L	L <sub>p</sub>	Q	v	w	y	Z <sup>(1)</sup>	θ
mm	1	0.15 0.00	0.85 0.60	0.12	0.27 0.17	0.23 0.08	2.1 1.9	2.4 2.2	0.5	3.2 3.0	0.4	0.40 0.15	0.21 0.19	0.2	0.13	0.1	0.4 0.1	8° 0°

**Notes**

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT765-1		MO-187				02-06-07

## Inverter

## 74AHC3G04; 74AHCT3G04

**DATA SHEET STATUS**

<b>LEVEL</b>	<b>DATA SHEET STATUS<sup>(1)</sup></b>	<b>PRODUCT STATUS<sup>(2)(3)</sup></b>	<b>DEFINITION</b>
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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**Limiting values definition** — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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